

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	28	("20020119629" "20020142543" "20020142545" "20030052361" "6077733" "6174767" "6225646" "6261905" "6435942" "6436764" "6436769" "6440796" "6441429" "6451654" "6451698" "6451699" "6455836" "6464855" "6465841" "6468863" "6479348" "6482700" "6486032" "6489649" "6492231" "6504206" "6524167" "6524915" "6528844" "6531732" "6531734" "6534821").PN.	USPAT	OR	OFF	2006/01/05 13:26
L2	50	("6287765" "5739254" "5753783" "5945253" "6151042" "5551142" "6063207" "6153479" "6033968" "6242342" "6146940" "6113069" "6182633" "5389182" "4284659" "5188191" "5489079" "5607882" "4856252" "5325952" "5452401" "5563084" "5655124" "5787297" "5877034" "6137708" "5590346" "5602854" "5606347" "6002946" "5565745" "5706237" "6056869" "6057924" "4257099" "4314521" "4519371" "5618149" "5645261" "5660451" "5674774" "5725194" "5998909" "6101094" "4455660" "5187853" "5297690" "4426251" "5376571" "5813752").pn.	USPAT	OR	OFF	2006/01/05 13:29
L3	222	438/267.ccls.	USPAT	OR	OFF	2006/01/05 13:30
L4	274	438/267.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/05 13:30
S1	61	("20020119629" "20020142543" "20020142545" "20030052361" "6077733" "6174767" "6225646" "6261905" "6435942" "6436764" "6436769" "6440796" "6441429" "6451654" "6451698" "6451699" "6455836" "6464855" "6465841" "6468863" "6479348" "6482700" "6486032" "6489649" "6492231" "6504206" "6524167" "6524915" "6528844" "6531732" "6531734" "6534821").PN.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/13 20:03

S2	6	flash and SGFET	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:43
S3	2	"6855602".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 20:10
S4	2	"6136710".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 20:10
S5	2	("20030129840" "20040036118").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/09/13 20:13
S6	1	("6855602").URPN.	USPAT	OR	OFF	2005/09/13 20:14
S7	56671	memory adj device and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:44
S8	3968	memory adj device and transistor and second adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:49
S9	2	Partially near2 memory adj device and Partially near2 transistor same first adj layer and second adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:58
S10	2	Partially near2 memory adj device and transistor same first adj layer and second adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:58
S11	938	memory adj device and transistor same first adj layer and second adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/15 19:58
S12	5	("5989960" "6143609" "6248633" "6255205" "6258668").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/05 10:37
S13	5	("6524915").URPN.	USPAT	OR	OFF	2006/01/05 10:45
S14	1	"6855602".pn.	USPAT	OR	OFF	2006/01/05 10:46
S15	1	"6136710".pn.	USPAT	OR	OFF	2006/01/05 13:19